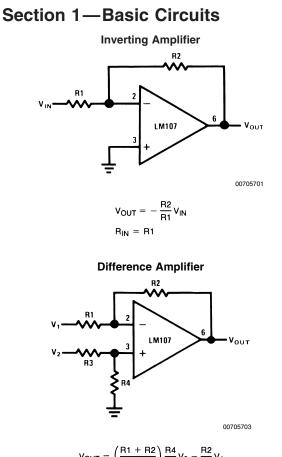
# **Op Amp Circuit Collection**

National Semiconductor Application Note 31 September 2002

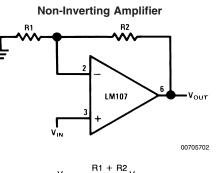


Note: National Semiconductor recommends replacing 2N2920 and 2N3728 matched pairs with LM394 in all application circuits.

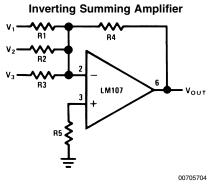


$$\begin{split} V_{OUT} &= \left(\frac{R1 + R2}{R3 + R4}\right) \frac{R4}{R1} V_2 - \frac{R2}{R1} V_1 \\ \text{For } R1 &= R3 \text{ and } R2 = R4 \\ V_{OUT} &= \frac{R2}{R1} (V_2 - V_1) \\ \text{R}1 // \text{R}2 &= R3 // \text{R}4 \end{split}$$

For minimum offset error due to input bias current

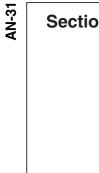




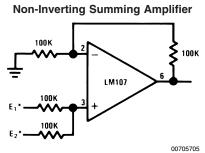


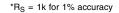
$$V_{\text{OUT}} = -\text{R4}\left(\frac{\text{V}_{1}}{\text{R1}} + \frac{\text{V}_{2}}{\text{R2}} + \frac{\text{V}_{3}}{\text{R3}}\right)$$

R5 = R1//R2//R3//R4 For minimum offset error due to input bias current

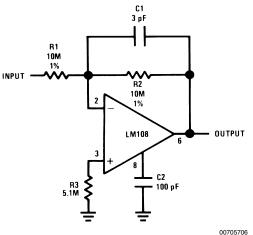


### Section 1—Basic Circuits (Continued)

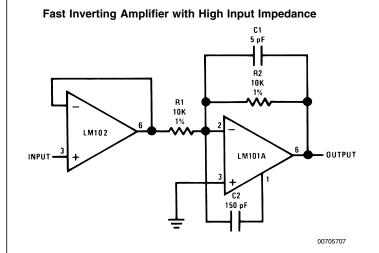


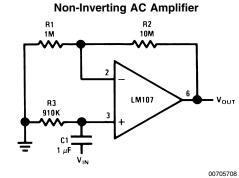


Inverting Amplifier with High Input Impedance

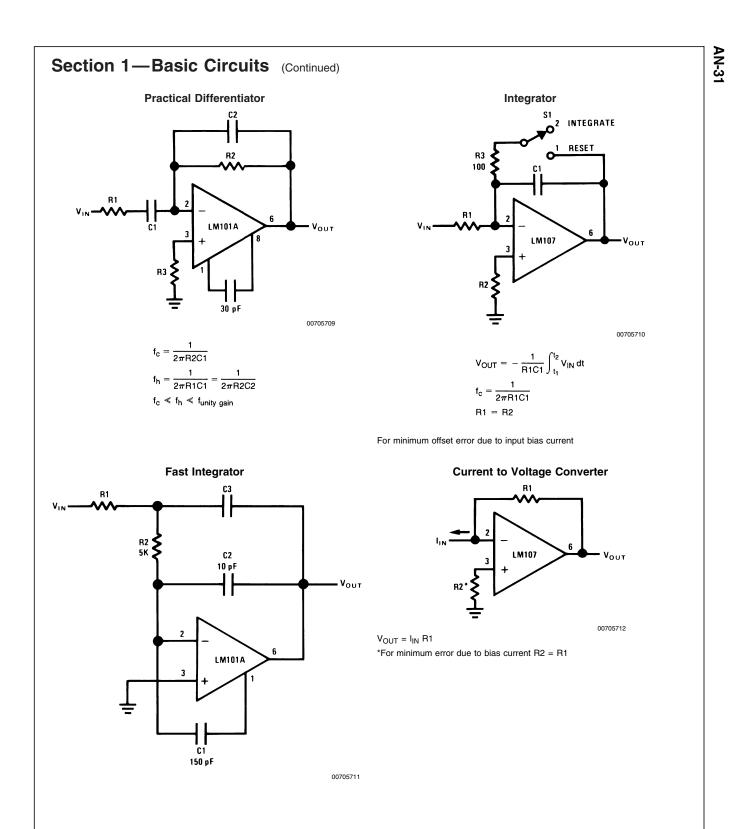


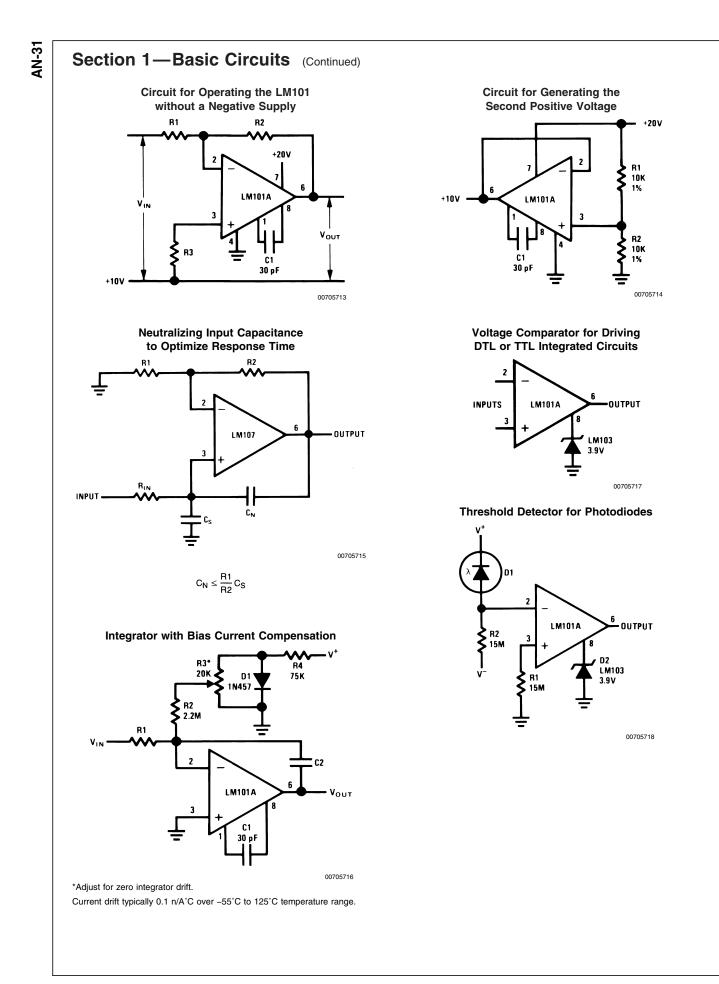
\*Source Impedance less than 100k gives less than 1% gain error.

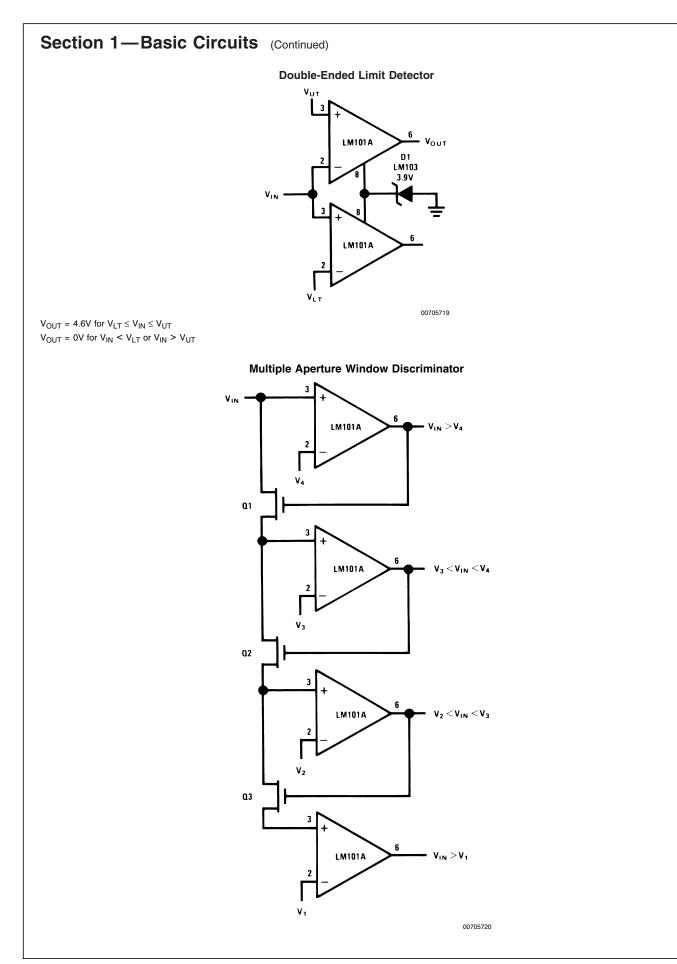








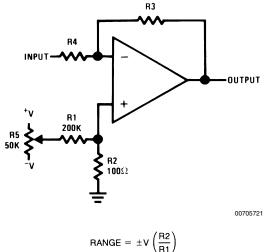




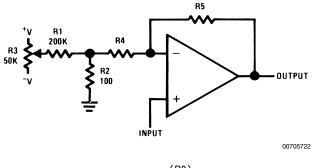


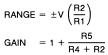
### Section 1—Basic Circuits (Continued)



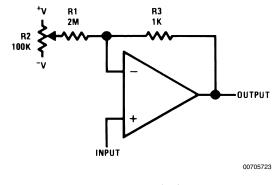






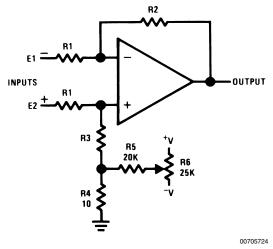


Offset Voltage Adjustment for Voltage Followers



$$\mathsf{RANGE} = \pm \mathsf{V}\left(\frac{\mathsf{R3}}{\mathsf{R1}}\right)$$

Offset Voltage Adjustment for Differential Amplifiers



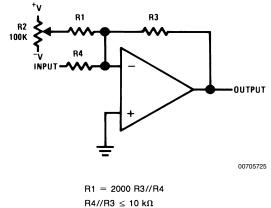
$$R2 = R3 + R4$$

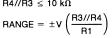
$$RANGE = \pm V \left(\frac{R5}{R4}\right) \left(\frac{R1}{R1 + R3}\right)$$

$$GAIN = \frac{R2}{R1}$$

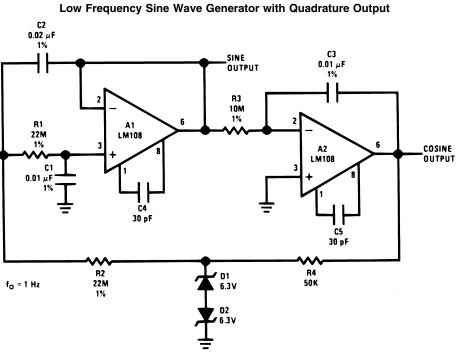
### Section 1—Basic Circuits (Continued)

Offset Voltage Adjustment for Inverting Amplifiers Using 10 k $\Omega$  Source Resistance or Less

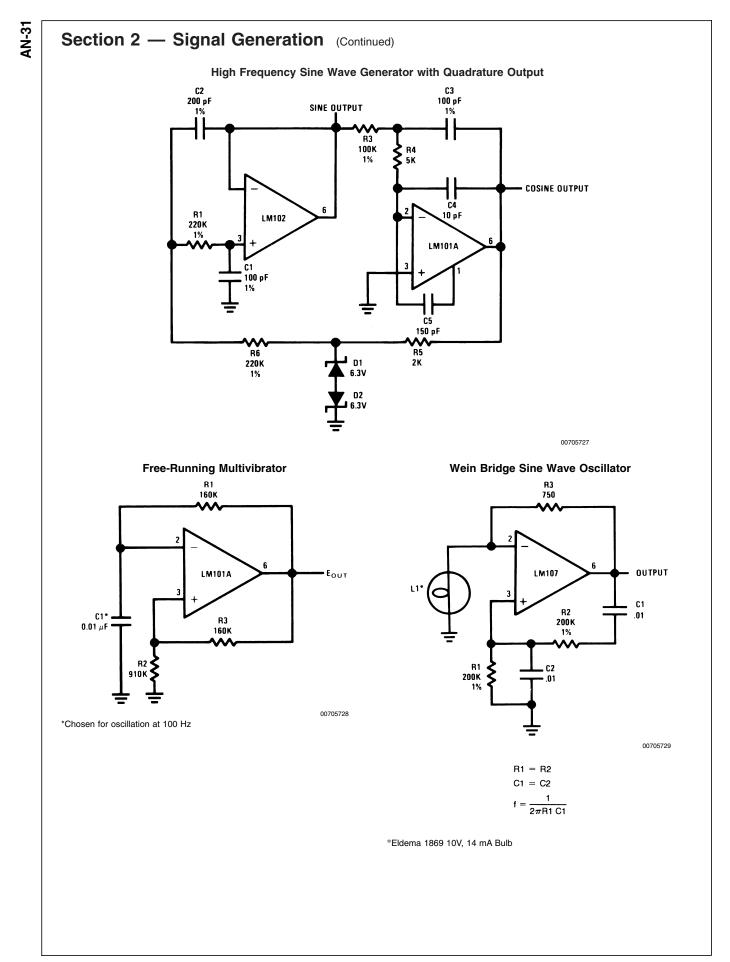


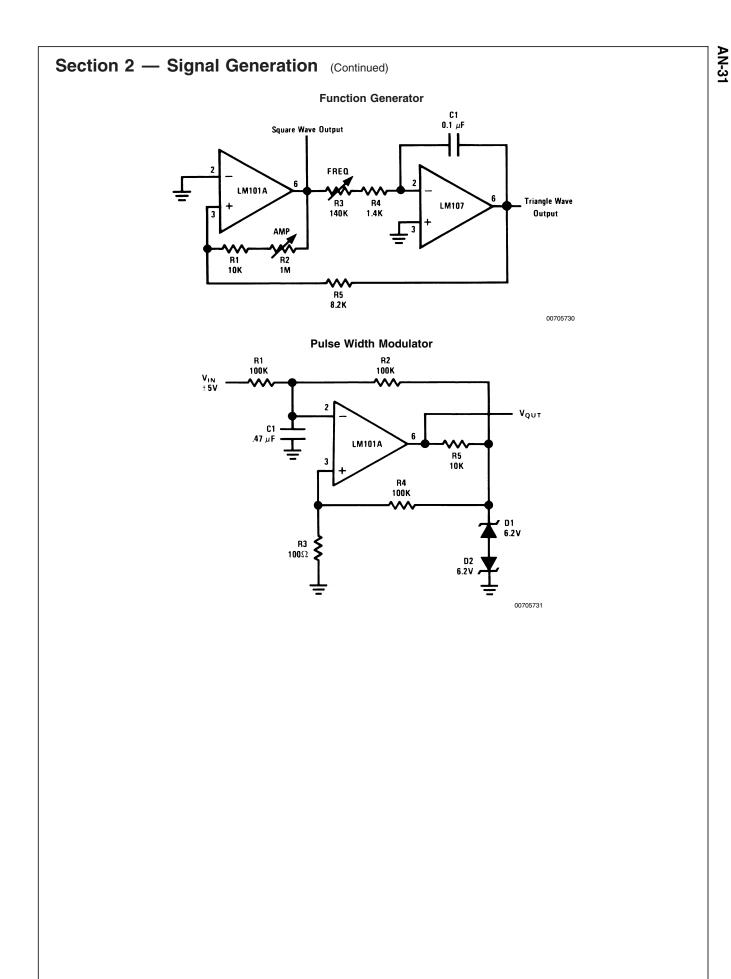


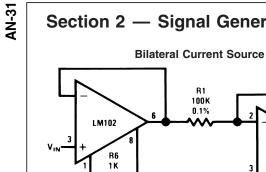
### Section 2 — Signal Generation



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BALANCE

# Section 2 — Signal Generation (Continued)

R3 50K 0.1% ξ

6

R5 Ş 500 1%

Ι<sub>ουτ</sub>

00705732

LM107

R4 49.5K 0.1%

R1 100K 0.1%

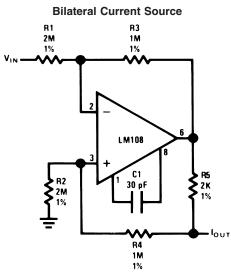
0.1%

R3 V<sub>IN</sub> R1 R5

R3 = R4 + R5

IOUT =

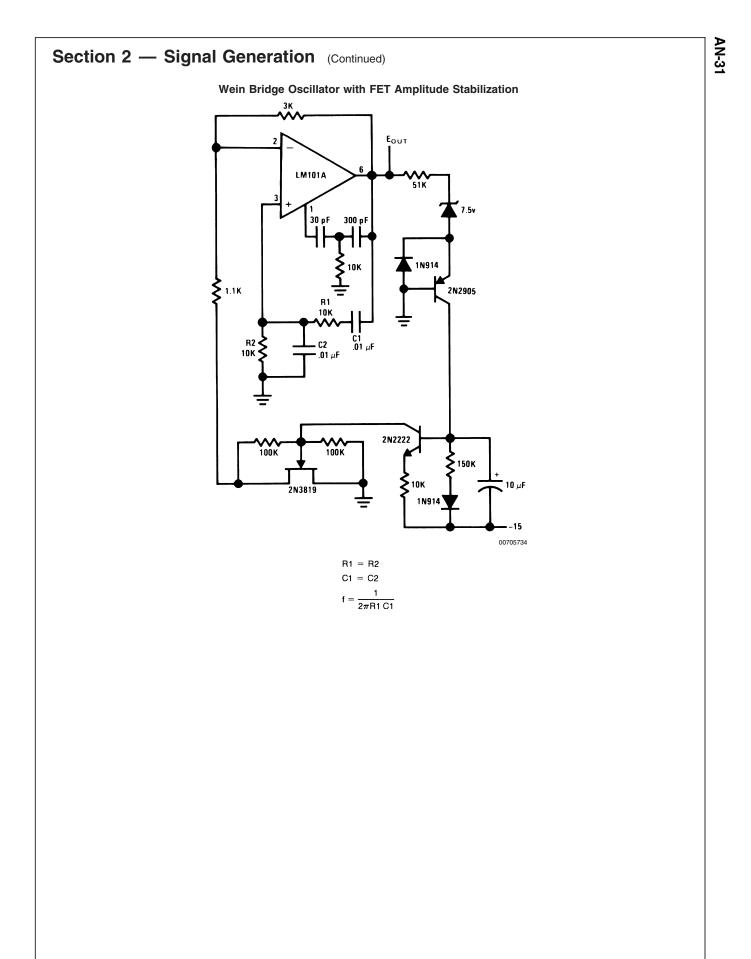
R1 = R2

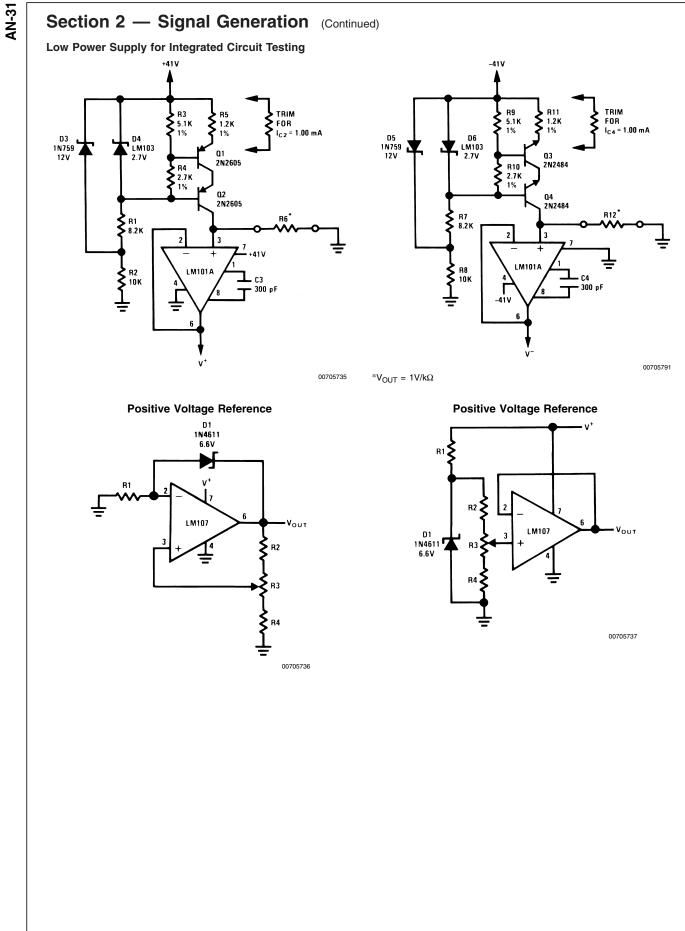


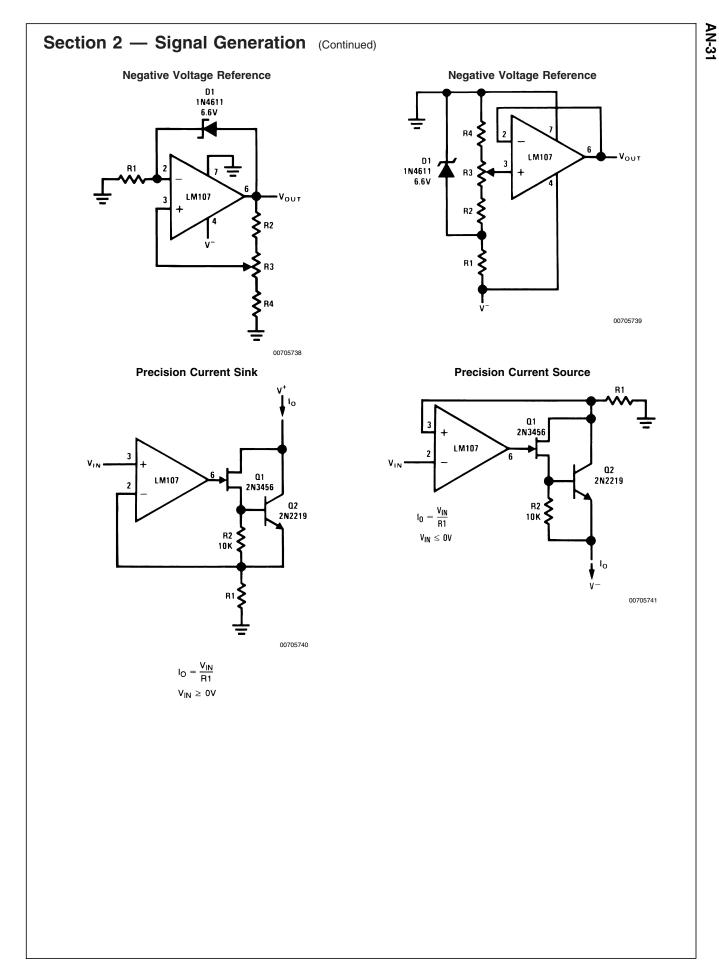
00705733

R3 V<sub>IN</sub> R1 R5 I<sub>OUT</sub> = R3 = R4 + R5R1 = R2

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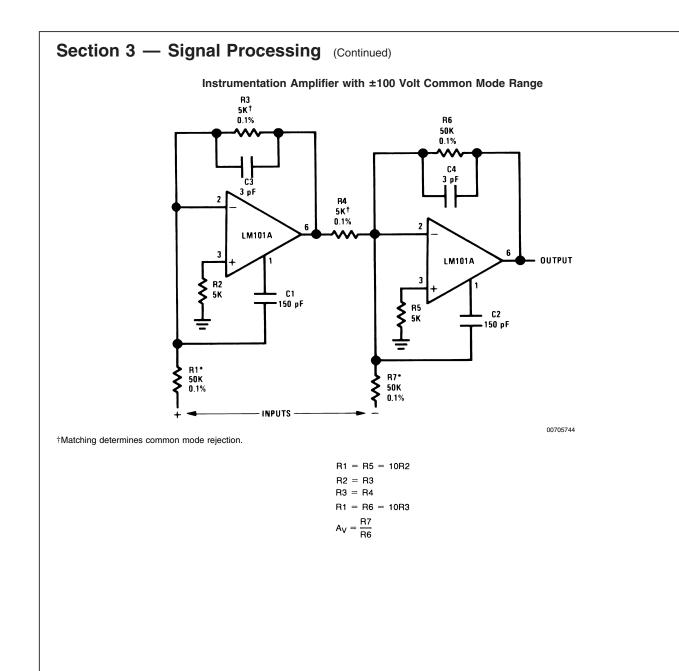
#### Section 3 — Signal Processing **Differential-Input Instrumentation Amplifier** R2 1K 0.1% R4 100K 0.1% £ LM102 3 2 Ł 6 LM107 OUTPUT INPUTS BALANCE R1 1K 3 8 3 LM102 R3 1K 0.1% R5 100K 0.1% 00705742 $\frac{R4}{R2}$ R5 R3 = $\frac{R4}{R2}$ $A_V =$ Variable Gain, Differential-Input Instrumentation Amplifier R5 10K R3 10K 0.1% 0.1% 6 LM102 3 - INPUT v+ BALANCE 4 6 LM107 INPUTS R1 1K 8 Ş 3 +INPUT-CŻ TO 3 MEG 5 pF LM102 R7 10K 0.1% Л 6 R4 10K 0.1% R2 10K 0.1% LM101A CI 150 pF \*Gain adjust

 $A_V = 10^{-4} \text{ R6}$ 

OUTPUT

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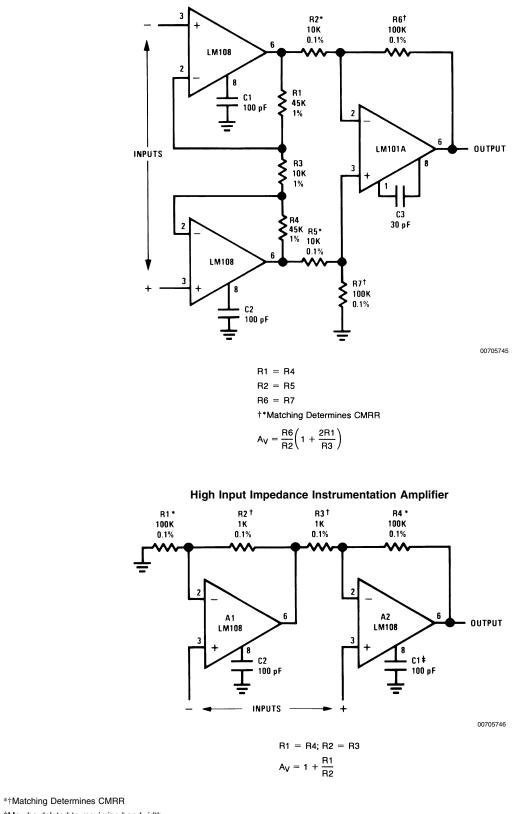
R6\* 10k



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**AN-31** 

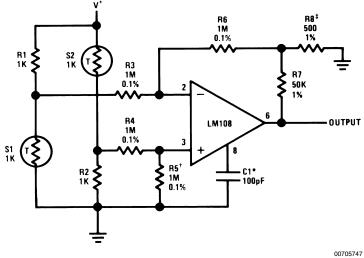
Instrumentation Amplifier with ±10 Volt Common Mode Range



#May be deleted to maximize bandwidth

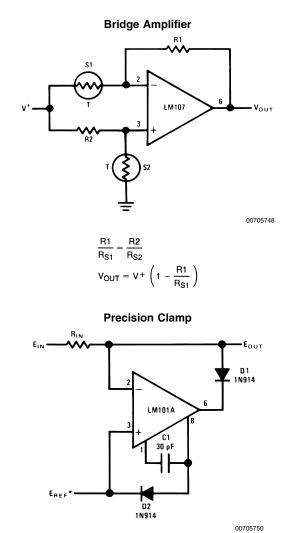
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#### Bridge Amplifier with Low Noise Compensation



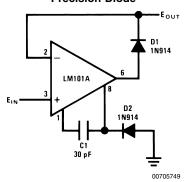
\*Reduces feed through of power supply noise by 20 dB and makes supply bypassing unnecessary. †Trim for best common mode rejection

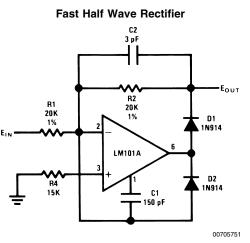
‡Gain adjust



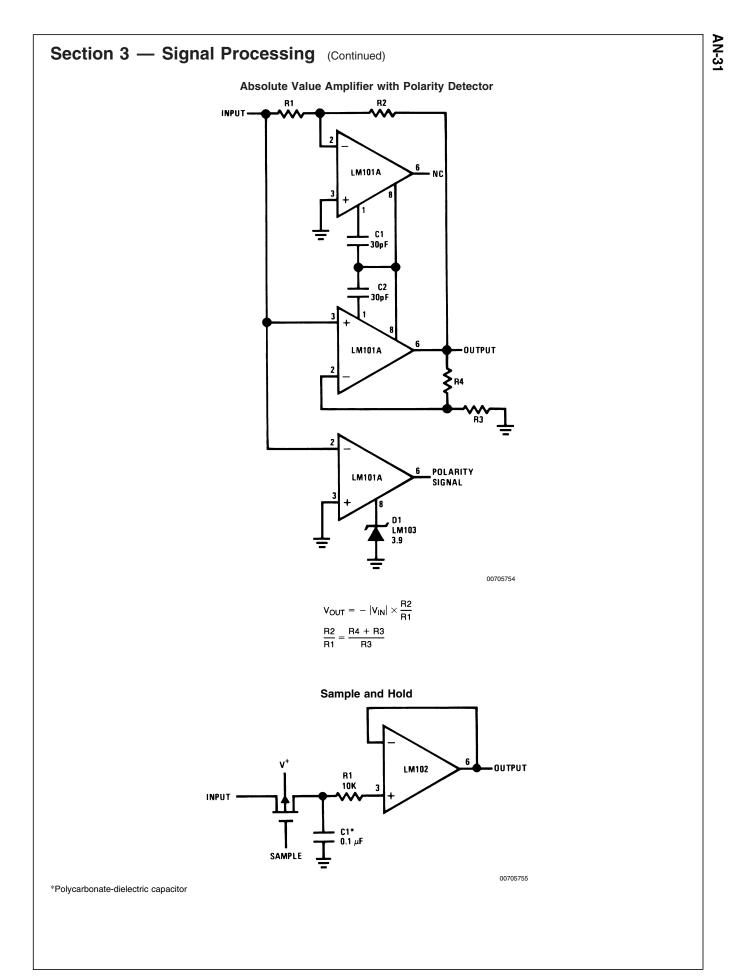
 ${}^{*}\mathsf{E}_{\mathsf{REF}}$  must have a source impedance of less than 200 $\Omega$  if D2 is used.

**Precision Diode** 

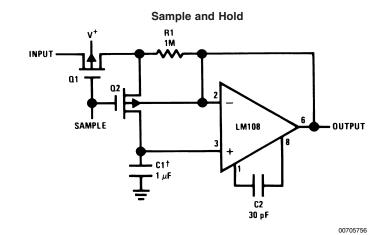




#### AN-31 Section 3 — Signal Processing (Continued) Precision AC to DC Converter R6 20K 1% C2 10 μF R2 20K R3 10k 1% 1% R7 22.2K Eout ~ R1 20K 1% D1 1**N914** 1% EIN 10 pF A2 A1 LM101A LM101A D2 R5 6.2K R4 15K 1N914 C1 150 pF C3\* 30 pF 00705752 \*Feedforward compensation can be used to make a fast full wave rectifier without a filter. Low Drift Peak Detector R3 20K D3 1N914 R1 1M H OUTPUT D2 1N914 LM102 D1 1N914 R2 10K 6 -LM101A — C2 — .01 μF 3 INPUT -Ī C1 30 pF 00705753

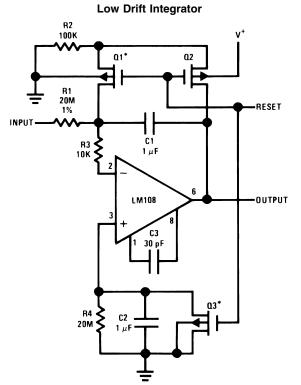






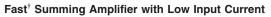
\*Worst case drift less than 2.5 mV/sec

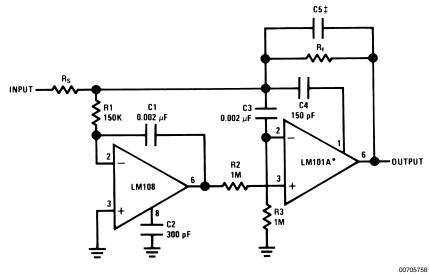
†Teflon, Polyethylene or Polycarbonate Dielectric Capacitor



00705757

\*Q1 and Q3 should not have internal gate-protection diodes. Worst case drift less than 500  $\mu V/sec$  over –55°C to +125°C.

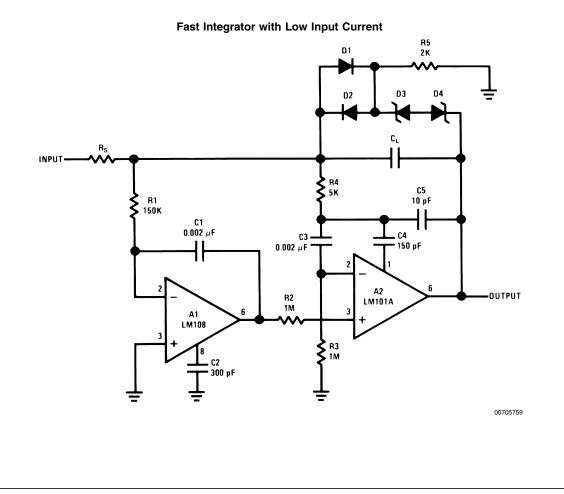




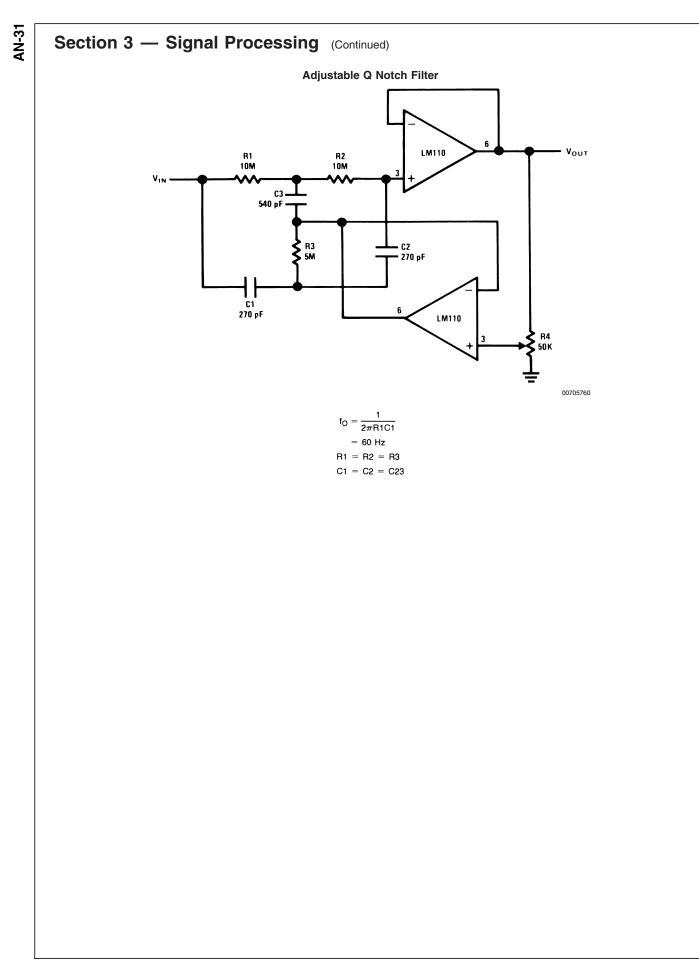
\*In addition to increasing speed, the LM101A raises high and low frequency gain, increases output drive capability and eliminates thermal feedback. †Power Bandwidth: 250 kHz

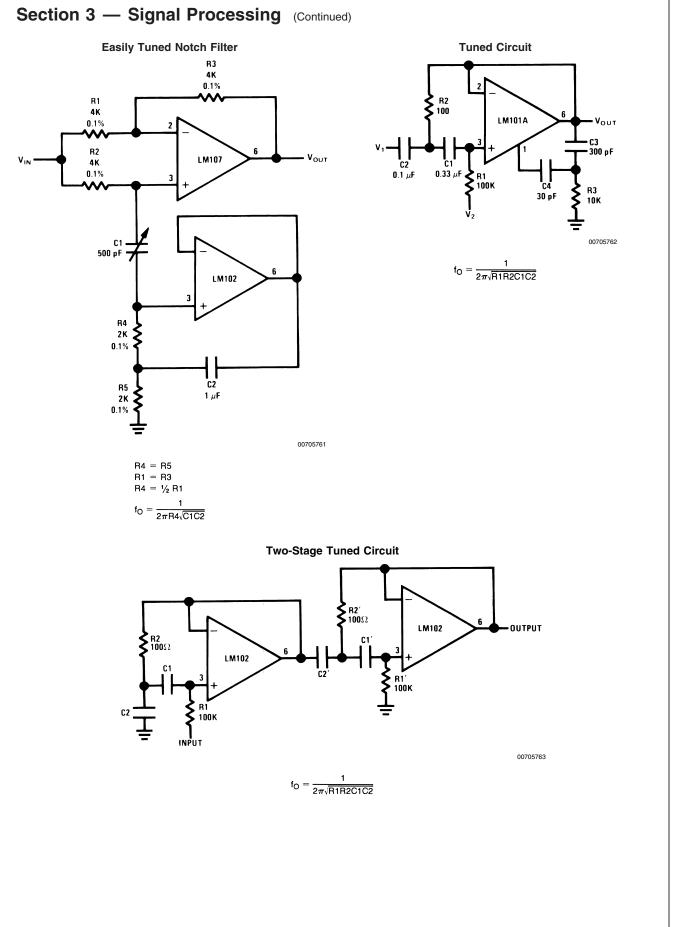
Small Signal Bandwidth: 3.5 MHz Slew Rate: 10V/µs

$$\ddagger C5 = \frac{6 \times 10^{-8}}{R_{f}}$$

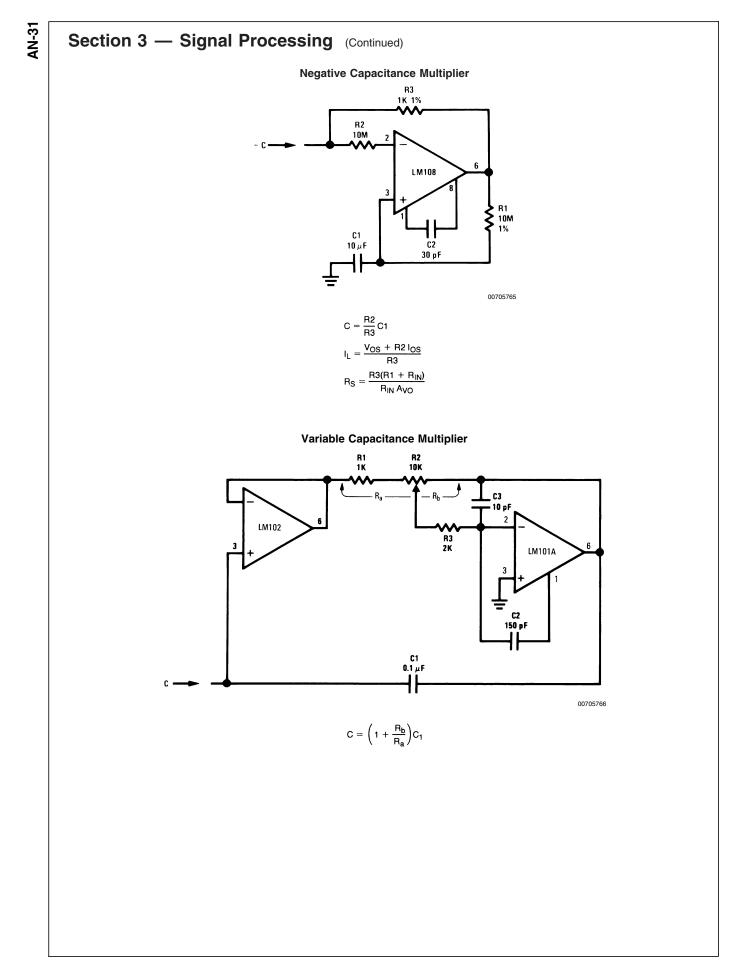


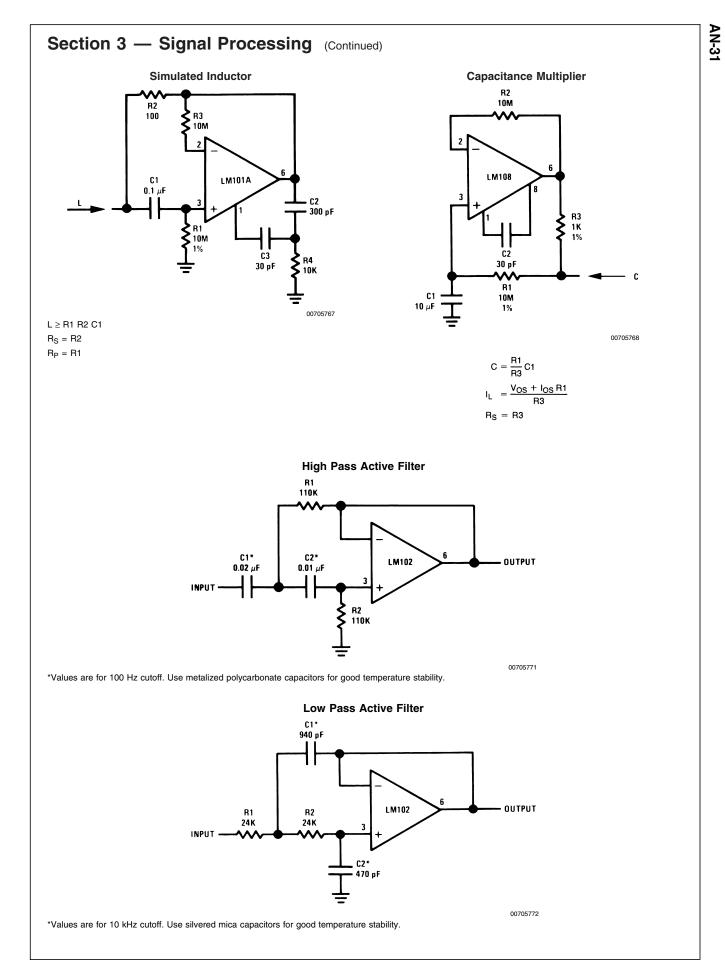
21

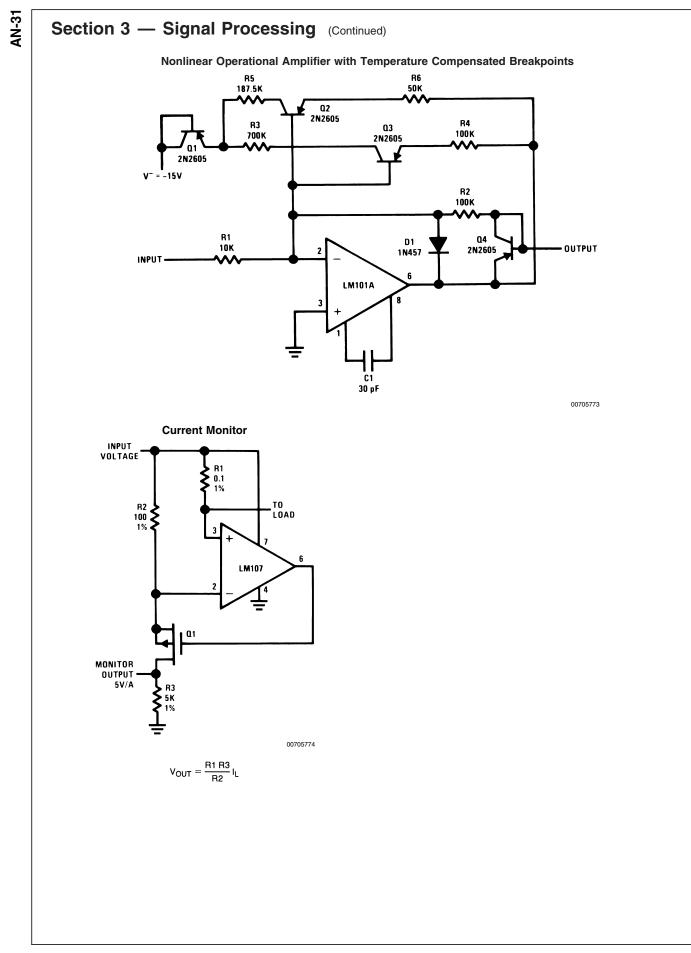


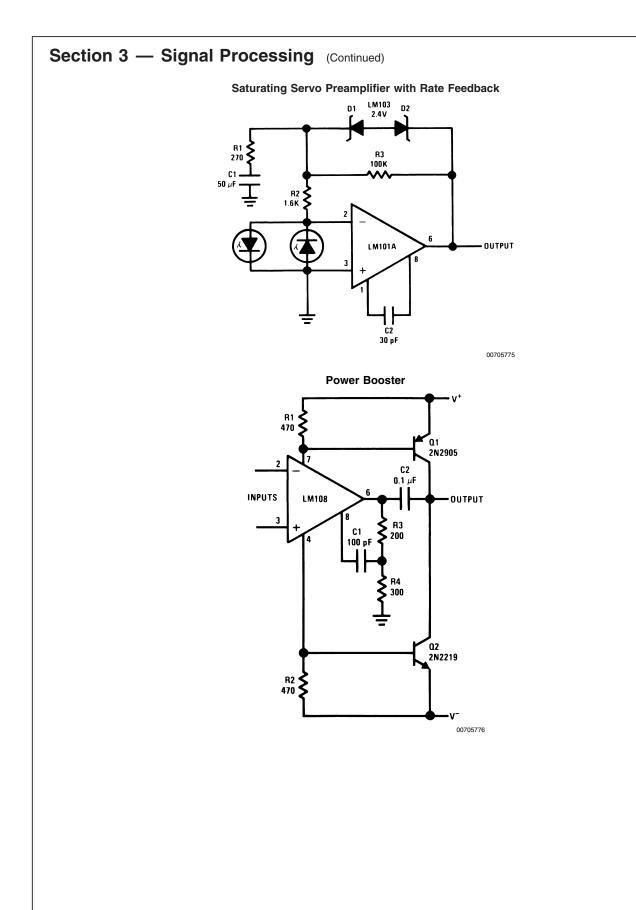


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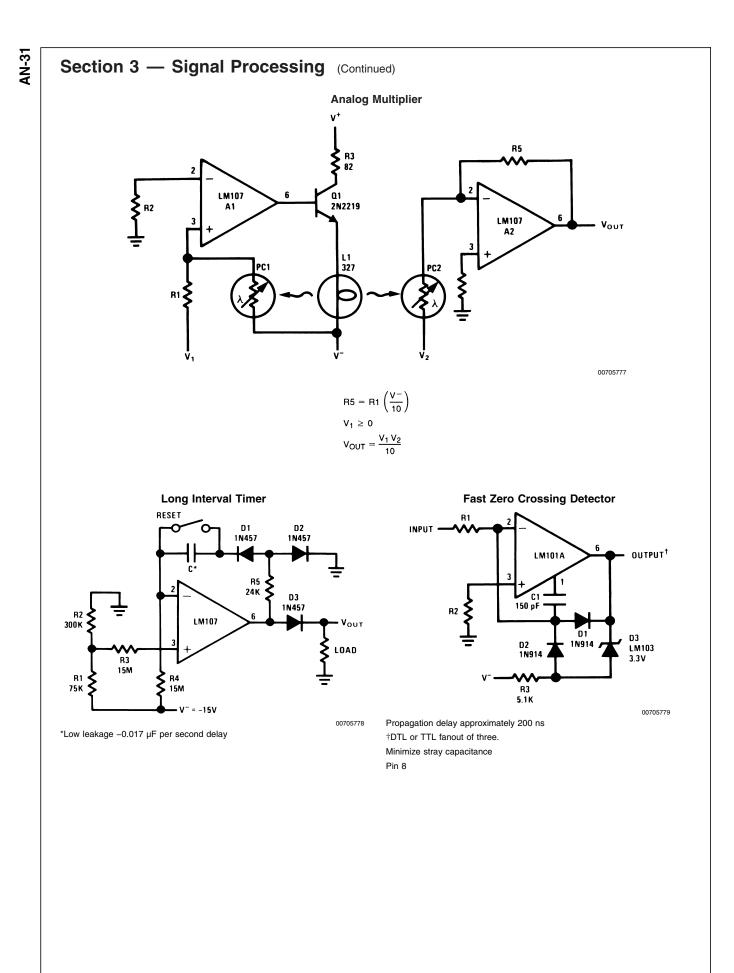


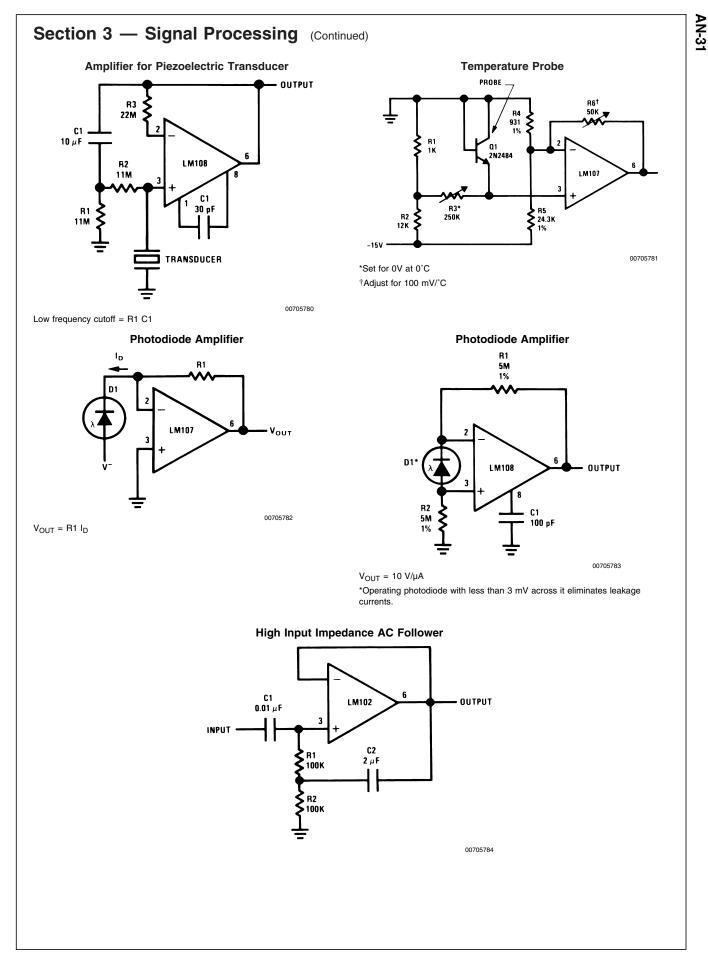






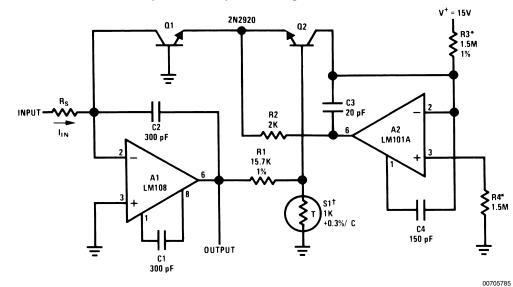
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## Section 3 — Signal Processing (Continued)



**Temperature Compensated Logarithmic Converter** 

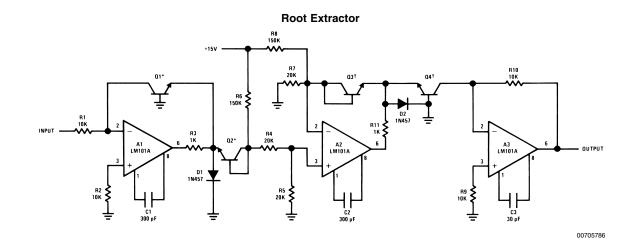
10 nA <  $I_{IN}$  < 1 mA

Sensitivity is 1V per decade

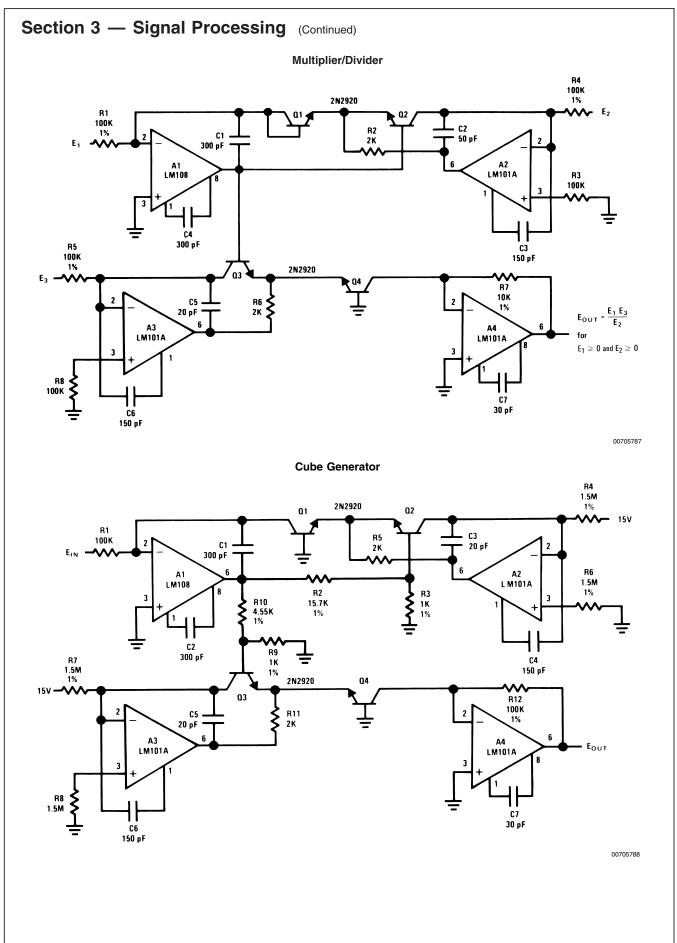
†1 k $\Omega$  (±1%) at 25°C, +3500 ppm/°C.

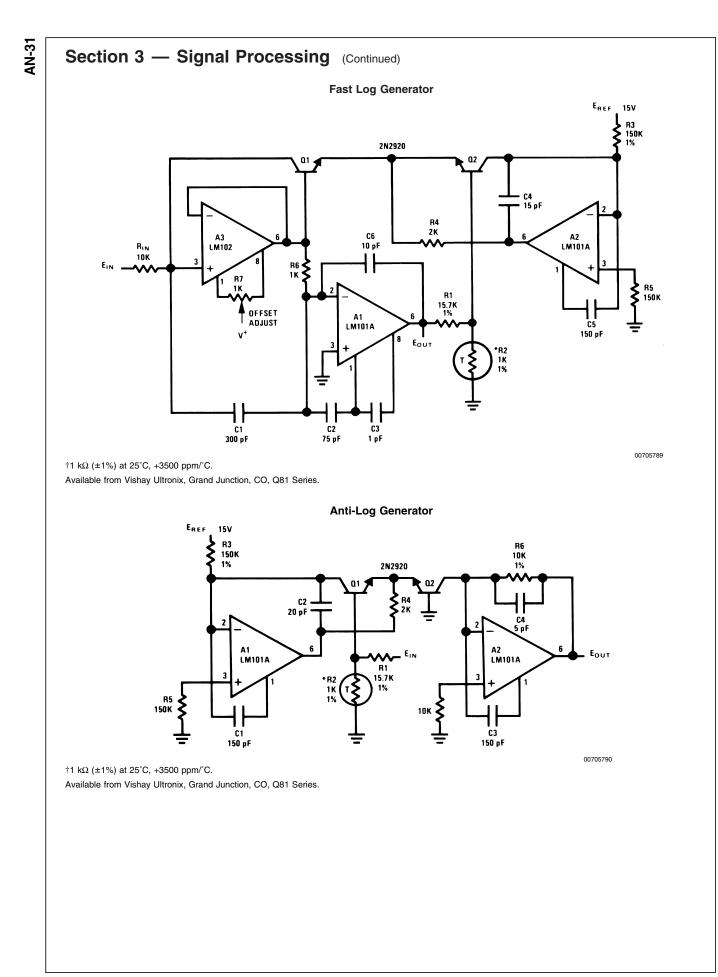
Available from Vishay Ultronix, Grand Junction, CO, Q81 Series.

\*Determines current for zero crossing on output: 10  $\mu A$  as shown.



\*†2N3728 matched pairs





### **Notes**

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